MA4X746 (MA746)

Silicon epitaxial planar type

For super high speed switching For small current rectification

Features

- Two isolated elements are contained in one package, allowing high-density mounting
- Forward current (Average) $I_{F(AV)} = 200 \text{ mA}$ and Reverse voltage $V_R < 50 \text{ V}$ are achieved
- Optimum for high frequency rectification because of its short reverse recovery time t_{rr}
- Low forward voltage V_F and good rectification efficiency

■ Absolute Maximum Ratings $T_a = 25$ °C

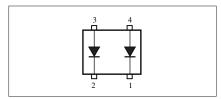
Parameter		Symbol	Rating	Unit
Reverse voltage		V_R	50	V
Repetitive peak reverse voltage		V _{RRM}	50	V
Non-repetitive peak	Single	I_{FSM}	1	A
forward surge current	Double *		0.75	
Peak forward	Single	I_{FM}	300	mA
current	Double *		225	
Forward current	Single	I _{F(AV)}	200	mA
(Average)	Double *		150	
Junction temperature		T _j	125	°C
Storage temperature		T _{stg}	-55 to +125	°C

Note) *: Value of each diode in double diodes used.

Unit: mm $2.90^{+0.02}_{-0.05}$ 1.9±0.2 (0.95)(0.95).50+0.25 $0.60^{+0.10}_{-0.05}$ 0.4 ± 0.2 1: Cathode 1 2: Cathode 2 3: Anode 2 4 : Anode 1 EIAJ: SC-61 Mini4-G1 Package

Marking Symbol: M3M

Internal Connection

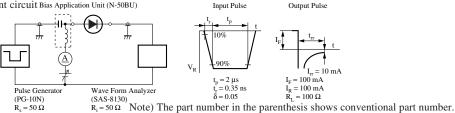


■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

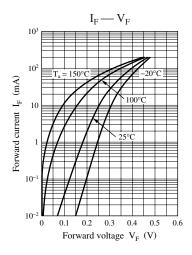
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V_{F1}	$I_F = 30 \text{ mA}$			0.36	V
	V_{F2}	$I_F = 200 \text{ mA}$			0.55	
Reverse current	I_R	$V_R = 50 \text{ V}$			200	μΑ
Terminal capacitance	C _t	$V_R = 0 V, f = 1 MHz$		30		pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 100 \text{ mA}$		3.0		ns
		$I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$				

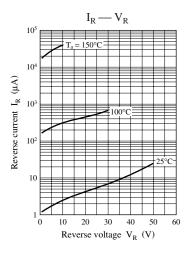
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

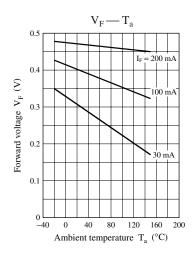
- 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. Absolute frequency of input and output is 1 GHz.
- 4. *: t_{rr} measurement circuit Bias Application Unit (N-50BU)

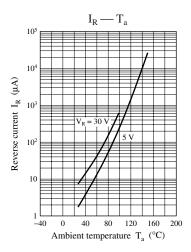


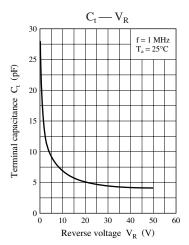
Panasonic











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